



# The ATLAS **D**iamond **B**eam **M**onitor



**Richard Kass**  
on behalf of the DBM group

**August 16, 2013**

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## Outline of Talk

Motivation

The ATLAS DBM Concept

DBM Design

DBM Status

Summary





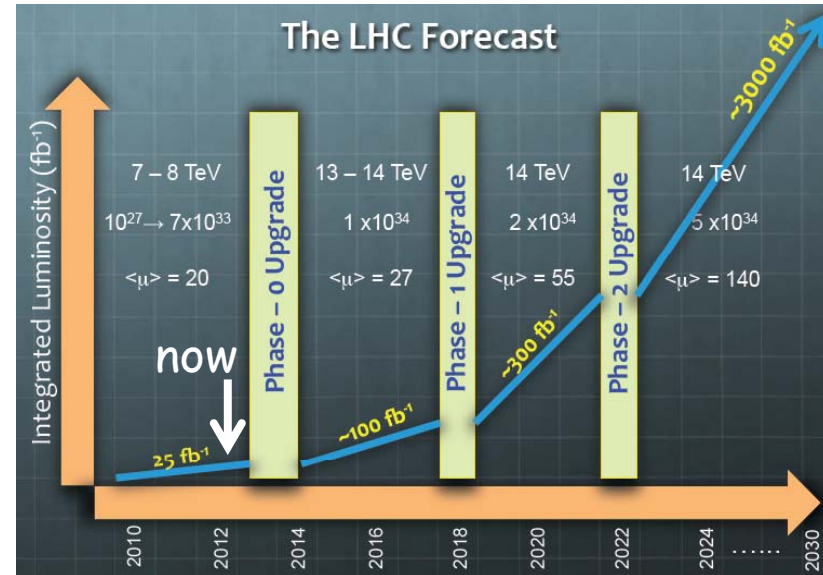
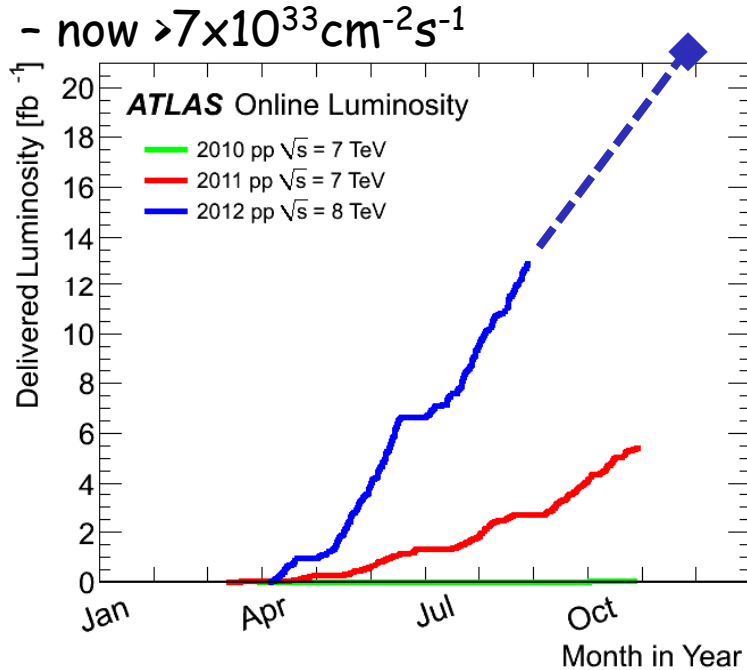
# Diamond Beam Monitor Motivation



Many precision measurements limited by luminosity determination  
(e. g. absolute cross section measurements,  $pp \rightarrow \text{Higgs}X, WZX, \dots$ )

Rapid increase in LHC Luminosity

...And L will continue to grow!



$$L = \mu(n_b f_r) / \sigma_{inel}$$

$\mu$  = average # of inelastic interactions per bunch crossing

$n_b$  = # of colliding bunch pairs

$f_r$  = machine revolution frequency

} LHC parameters

$\sigma_{inel}$  = inelastic cross section

Luminosity is a counting issue: requires good segmentation in space or time

Problems occur when  $\mu$  can not be reliably measured



# Diamond Beam Monitor Motivation



In order to make a precise determination of the luminosity at the highest instantaneous luminosity & energy we need a detector that is:

radiation hard: accumulate  $2 \times 10^{15} n_{eq}/cm^2$

fast:  $\sim$ nsec resolution, resolve beam bunches

stable/reliable: last for  $\sim$  "10 years"

sensitive to charged particles: prefer min. ionizing

Diamond is a good sensor candidate...

😊 radiation hard

😊 short collection time

😊 low leakage current

😊 excellent thermal conductor

😞 signal size  $\sim 2.5$  less than silicon for same thickness



# ATLAS already has 2 diamond based systems

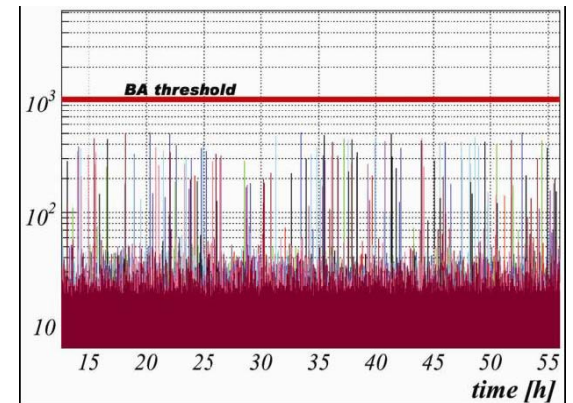
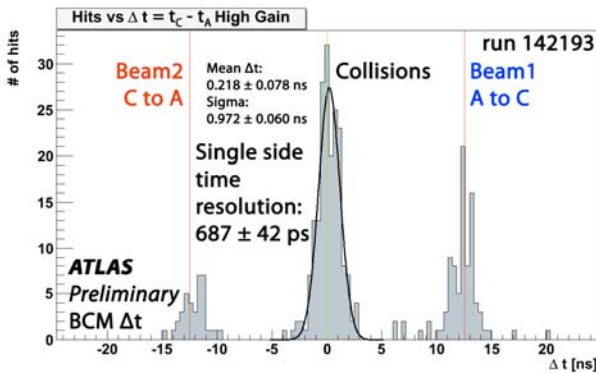
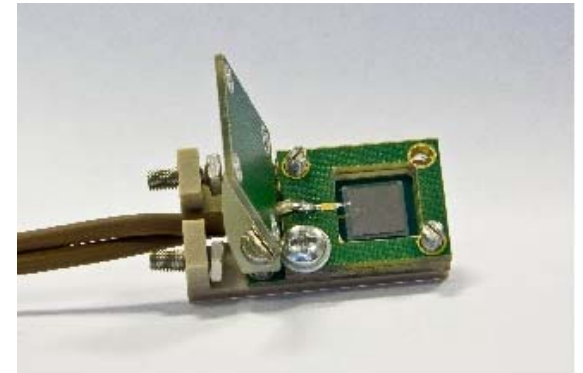
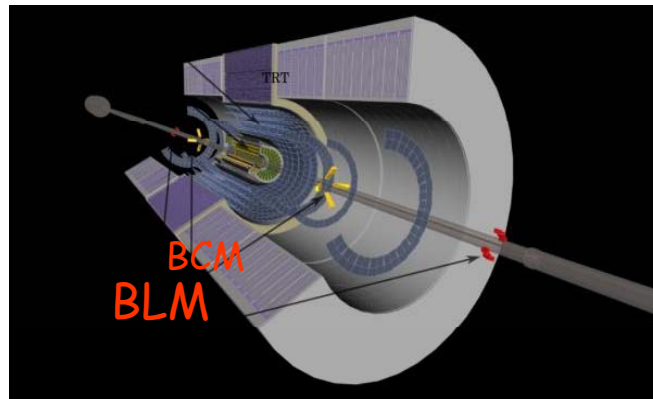
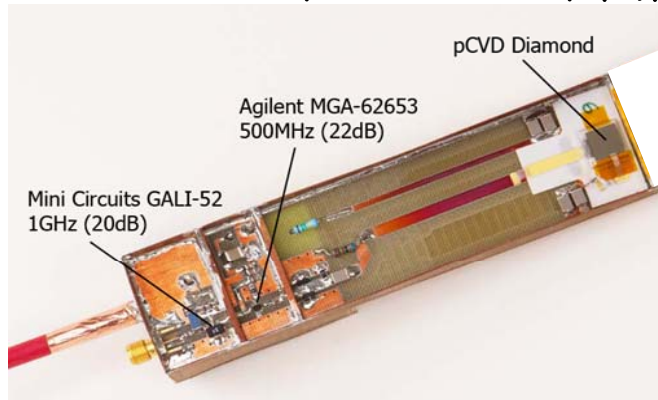


## Beam Conditions Monitor (BCM)

16 pCVD diamonds (1 x 1 cm<sup>2</sup>)  
z = ±184 cm, r = 5.5 cm, |η| = 4.2

## Beam Loss Monitor (BLM)

12 pCVD diamonds, 6 per side  
z = ±345 cm, r = 6.5 cm



**Both of these systems monitor the LHC beams:  
can abort the LHC beams  
essential for determining luminosity**

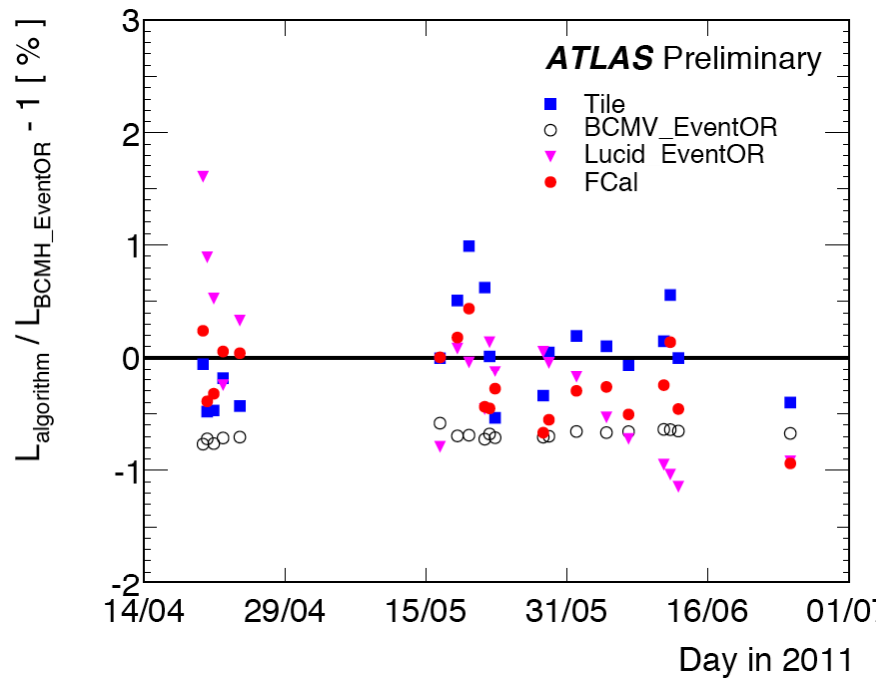


# DBM Motivation: lessons learned

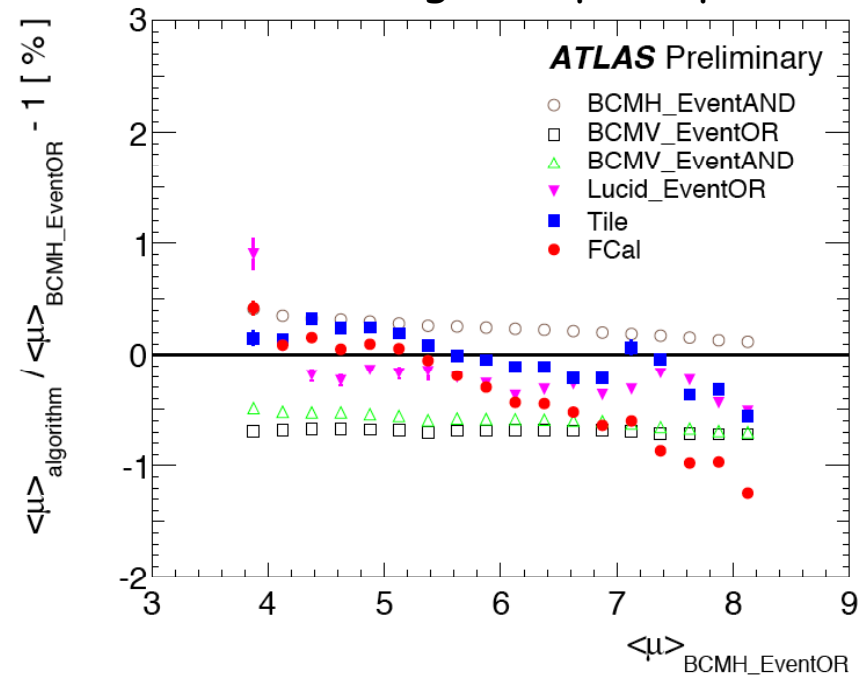


Two independent luminosity measurements BCMH & BCMV:  
(H=horizontal, V=vertical)

Stable over months



Stable against pile-up



In 2012 BCM achieved a 1.9% luminosity measurement!  
(BUT issues with vDM scans increased systematic error to ~3.5%)

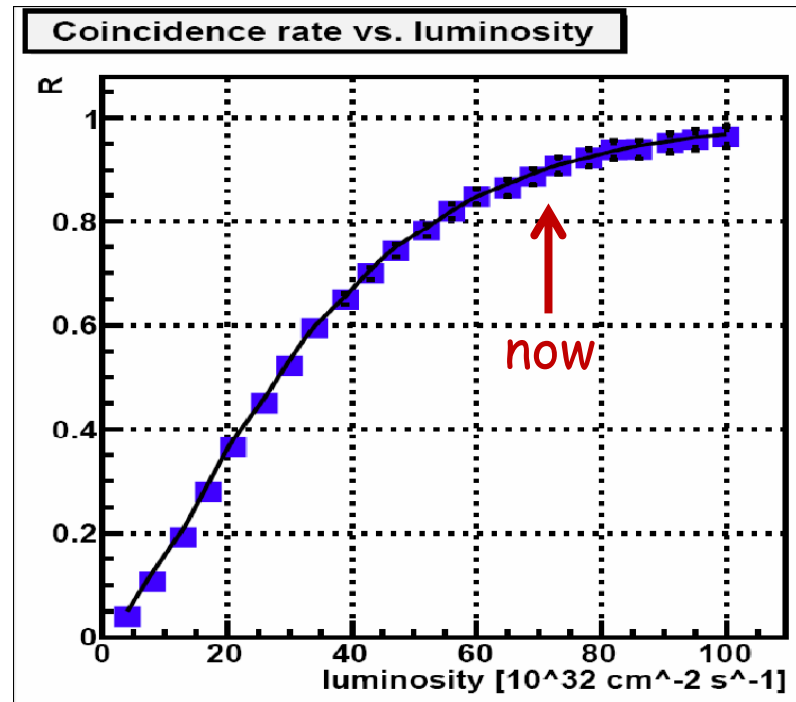




# DBM Motivation



The BCM will begin to saturate at  $\sim 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$ : 😞



More segmentation  $\rightarrow$  Diamond Beam Monitor (DBM) 😊

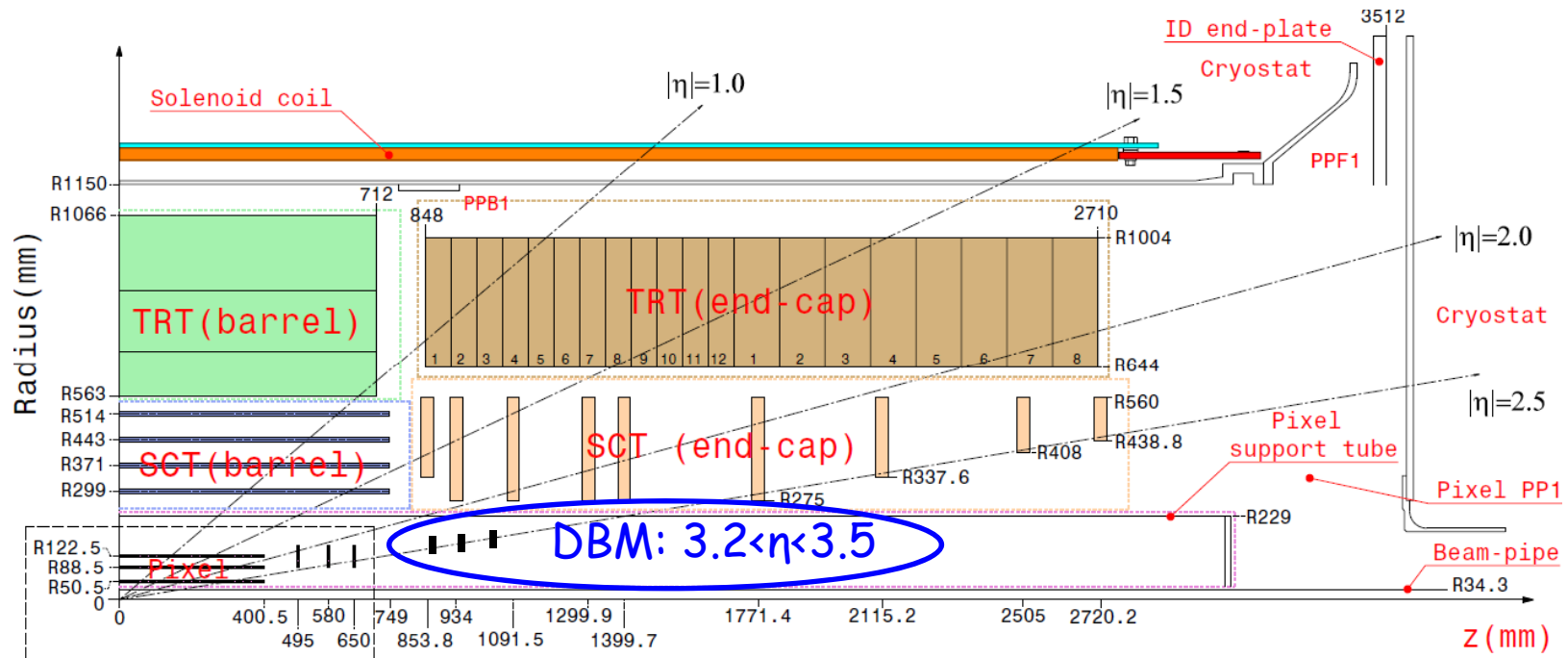
Increase number of channels by  $\sim 10^5$



# The ATLAS DBM Concept

Build on success of BCM - pixelate the sensors

- Use IBL diamond pixel demonstrator module
  - use many of the same pieces (FEI4, etc) as IBL to save time/money
  - same segmentation as IBL sensors,  $50 \times 250 \mu\text{m}^2$
- Install during new Service Quarter Panel (nSQP) replacement
- Four 3-plane stations on each side of the IR





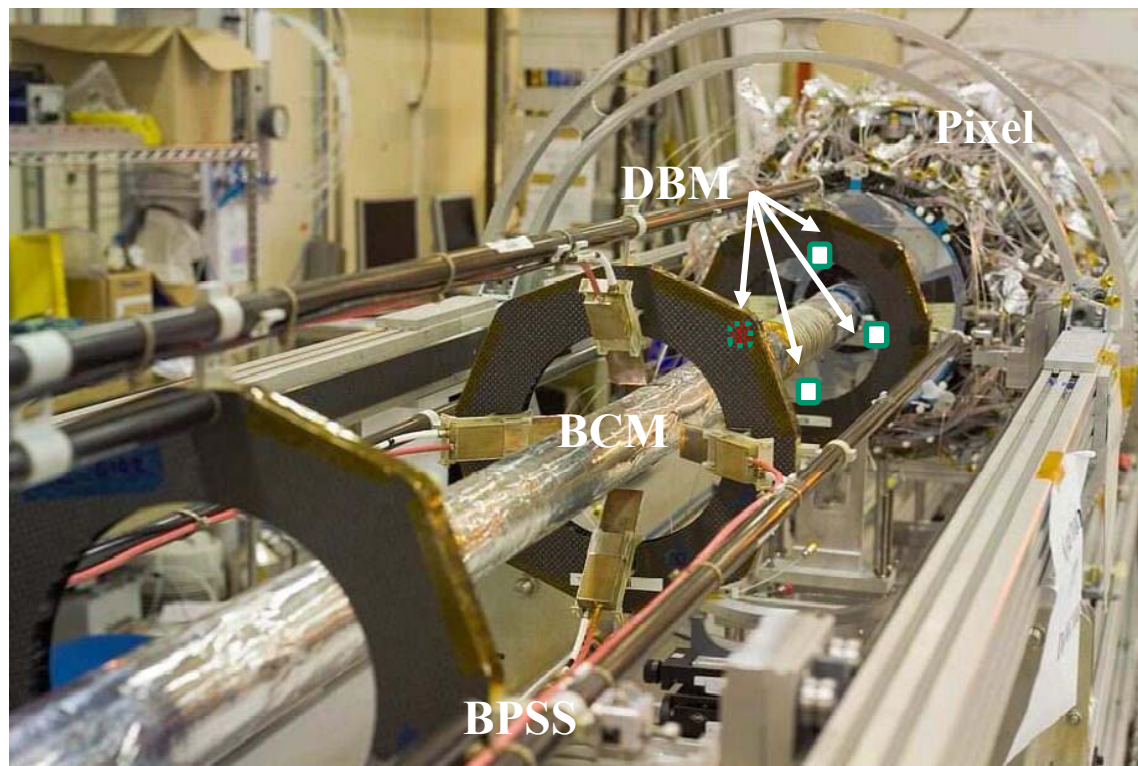
# The ATLAS DBM Concept



24 diamond pixel modules arranged in 8 telescopes provide

- Bunch by bunch luminosity monitoring
- Bunch by bunch beam spot monitoring

Installation happening now!







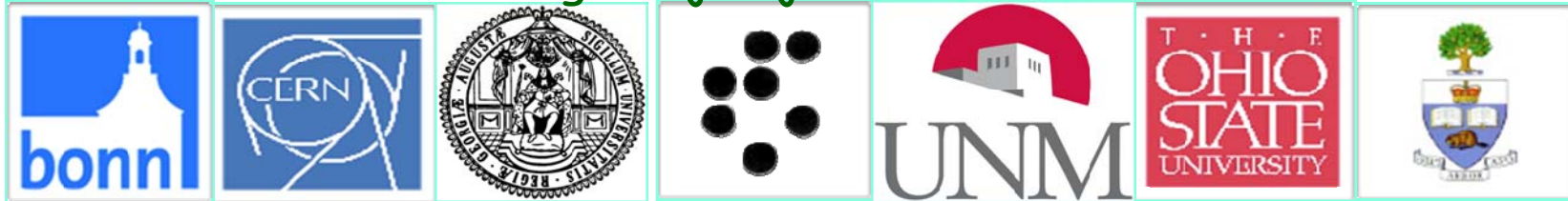
# The ATLAS DBM Specs and Collaboration



## Specs:

- Bunch by bunch luminosity monitoring ( $<1\%$  stats/sec)
- Bunch by bunch beam spot monitoring (unbiased sample,  $\sim 1\text{cm}$ )

Bonn CERN Göttingen Ljubljana N.Mexico OhioSt Toronto





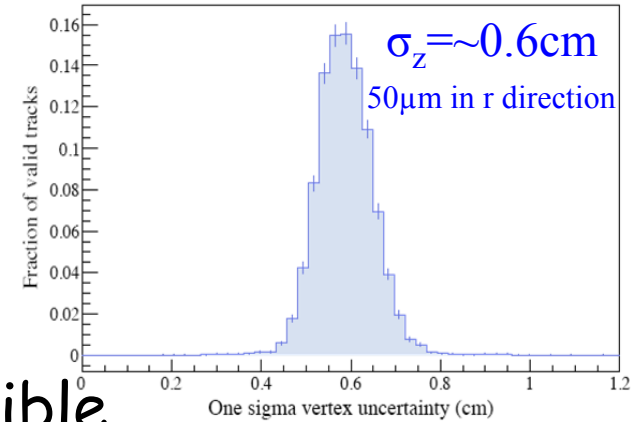
# The ATLAS DBM Concept



Simulate DBM to find best orientation and resolution

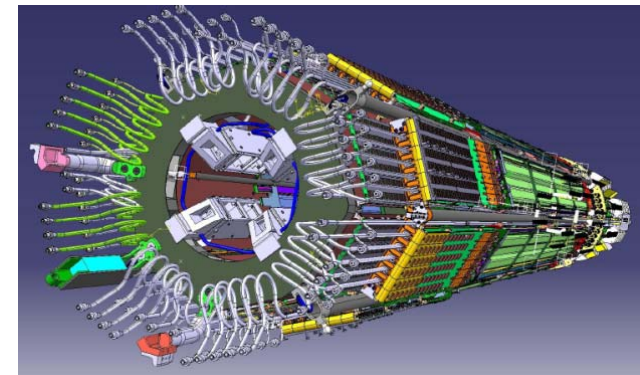
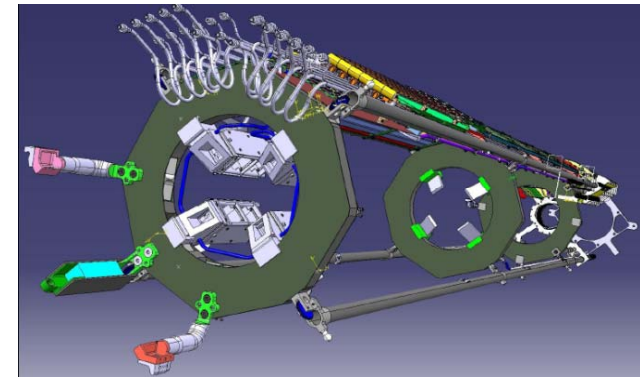
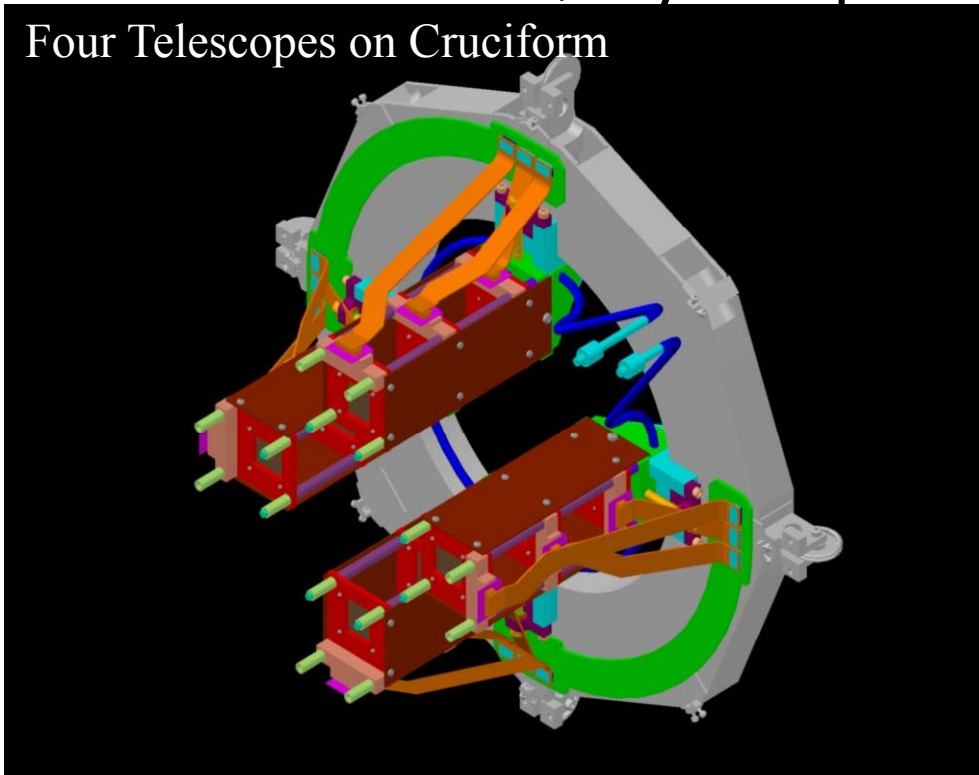
Focus on z vertex resolution

3 layers of tracking with  $50 \times 250 \mu\text{m}^2$  pixel cell



Mechanics: use as many IBL parts as possible

Four Telescopes on Cruciform





# DBM Diamond Sensor Plan



## Diamond Sensors for DBM:

Type: polycrystalline CVD diamond

Charge collection distance  $> 250 \mu\text{m}$

(as measured with Sr90 source)

Size:  $21 \times 18 \text{ mm}^2$ ,  $525 \pm 25 \mu\text{m}$  thickness

Number: 24 for DBM modules + spares

5 for Irradiation studies



$21 \times 18 \text{ mm}^2$  pCVD diamond

## Two diamond suppliers involved:

II-VI (US based)

Diamond Detectors Limited (DDL)/E6 (UK based)

☹ DDL ceases operations while filling our order....



# How much Diamond is in the DBM?



About as much as in the diamond Richard Burton bought for Liz Taylor in 1969

~ 70 carats

Auctioned in 1978 for \$5M

[http://en.wikipedia.org/wiki/Taylor-Burton\\_Diamond](http://en.wikipedia.org/wiki/Taylor-Burton_Diamond)



Each DBM sensor is ~ 3.2 carats  
(1 carat= 200 mg)

Entire DBM: 24 sensors

~ 76 carats!

Price of all DBM diamond < \$150k



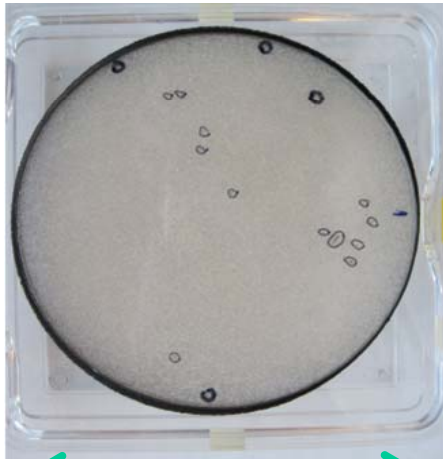


# DBM Diamond Sensor Qualification

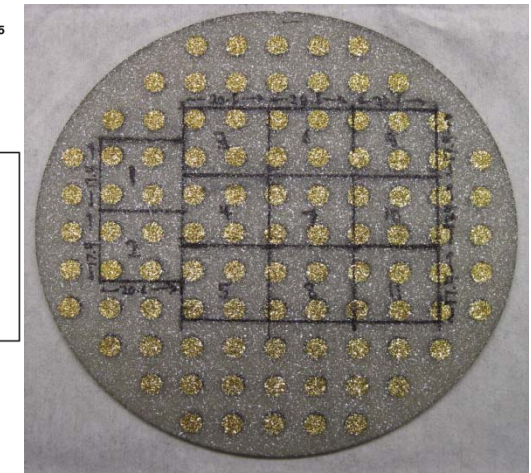
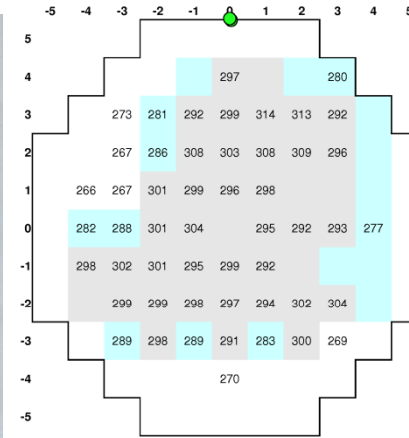
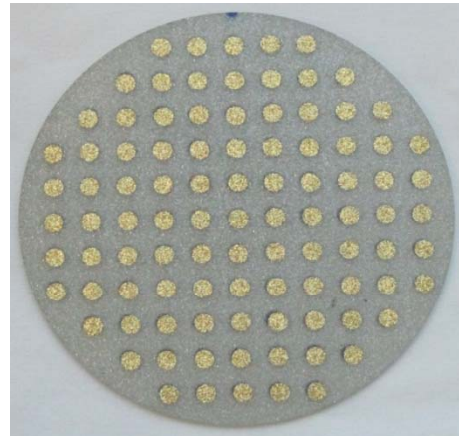


At OSU we put conducting contacts ("gold dots") on the diamond & measure the charge collection properties in the region of each dot.

Use Sr90 as a source of particles for charge collection measurements



5 inches



We also make a map of the current draw as we measure CCD  
Good regions have  $I < 5 \text{ nA}$  at 1000V in air



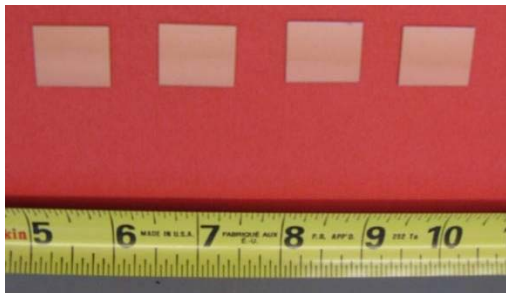


# DBM Module Production

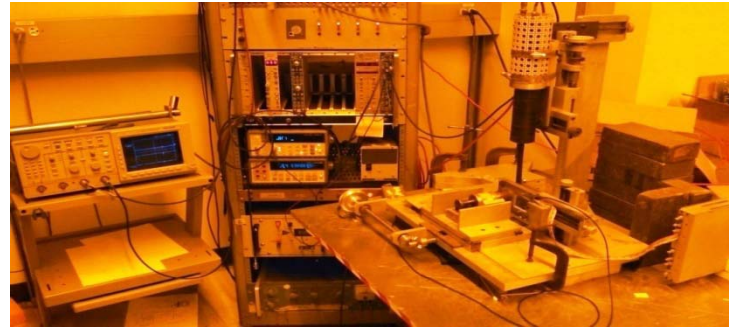


## Wafer is cut into pieces and shipped back to OSU

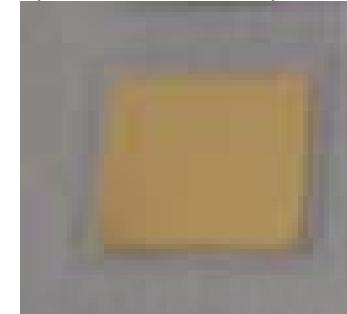
sensors



collection distance re-measured

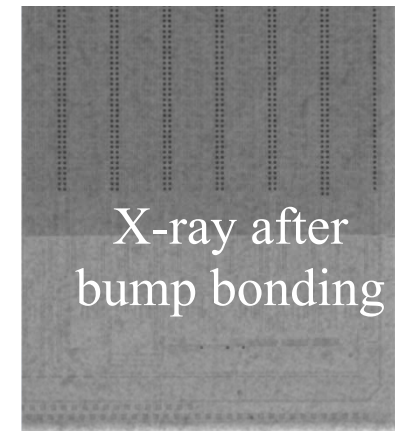
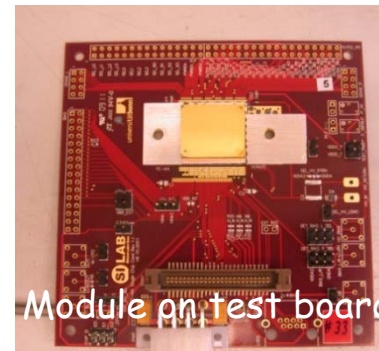
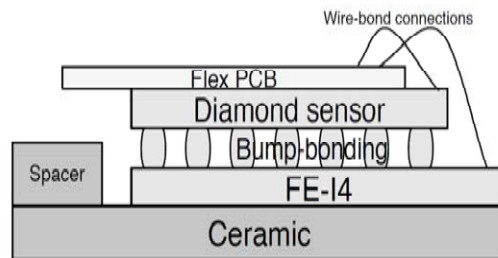


backplane is deposited



## Sensors are sent to IZM to be made into modules

put pixel pattern on diamond  
bump bond diamond to FEI4



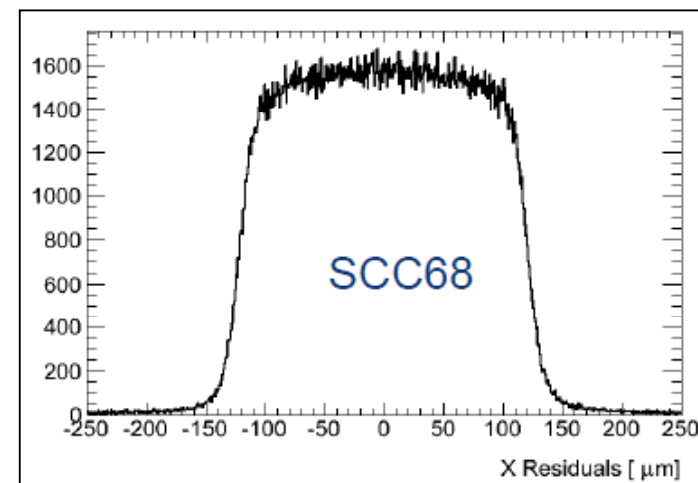
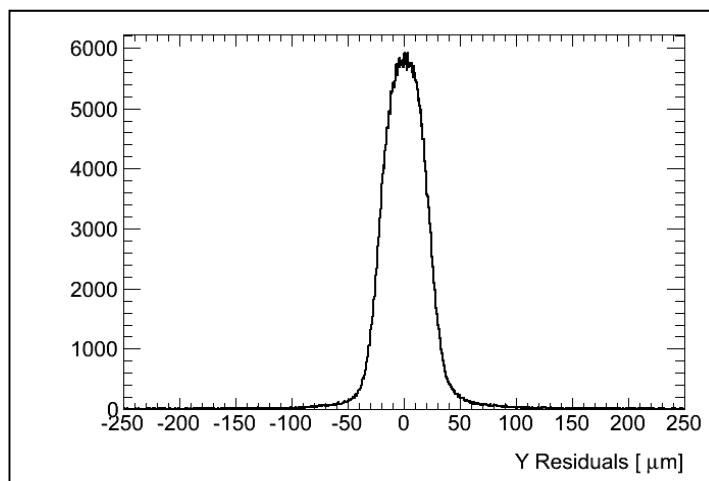
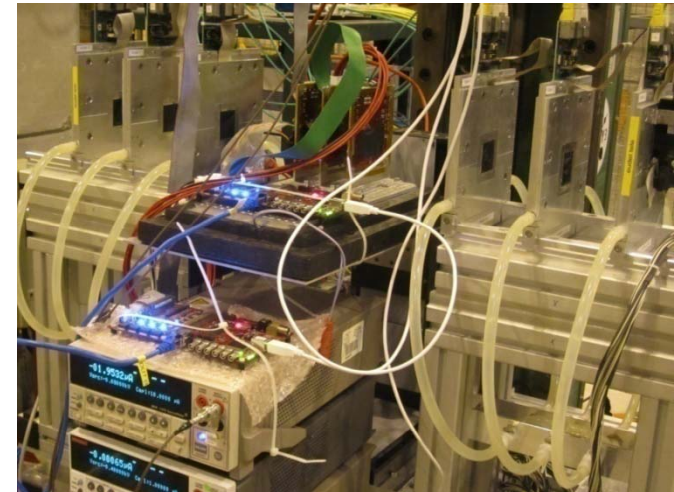
# DBM Module Testbeam Studies

Three Testbeam campaigns  
 Learning about FE-I4 performance  
 Calibration/tunings for low threshold performance

Prototype Modules Tested:

21mmx 18mm pCVD diamond w/FE-I4A  
 336 x 80 = 26880 channels  
 50 x 250  $\mu\text{m}^2$  pixel cell

Results: Noise map uniform, Efficiency >95%, spatial resolution digital





# OSU's DBM Hitbus Chip Overview

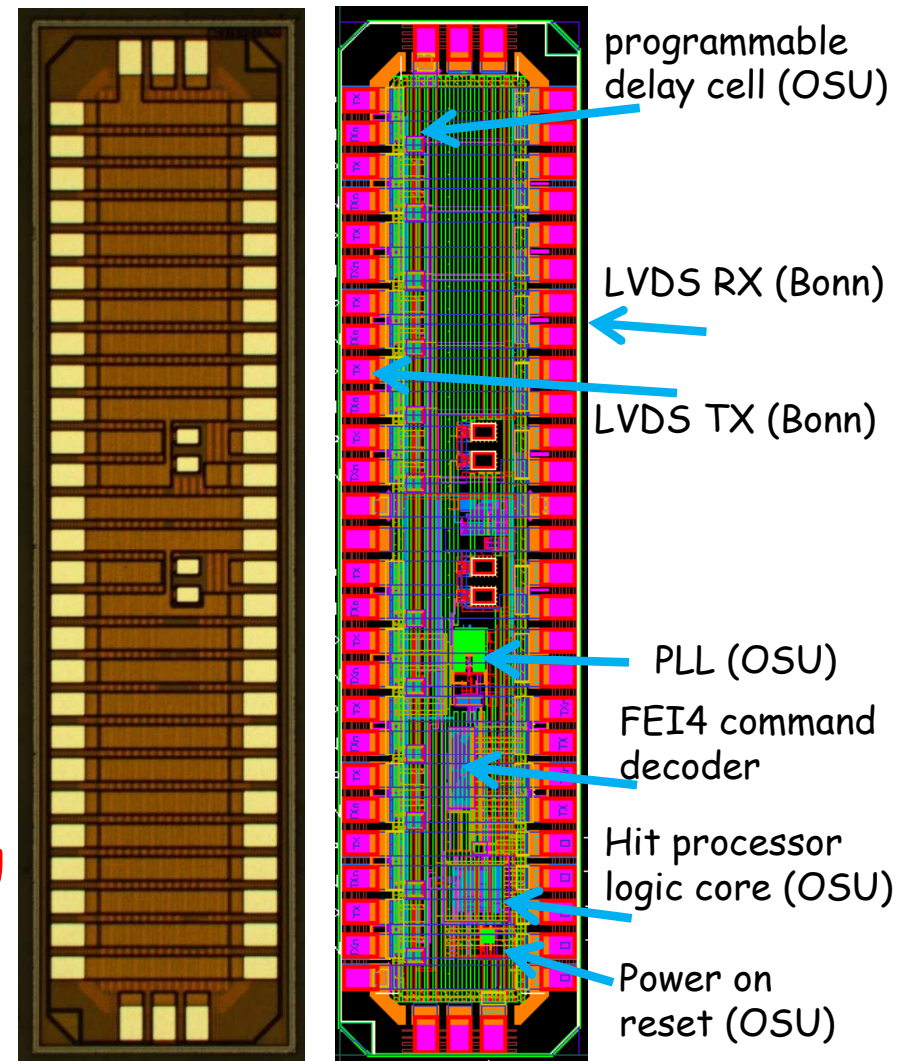


ASIC developed to provide L1A trigger for the DBM by using the FEI4 Hitbus outputs

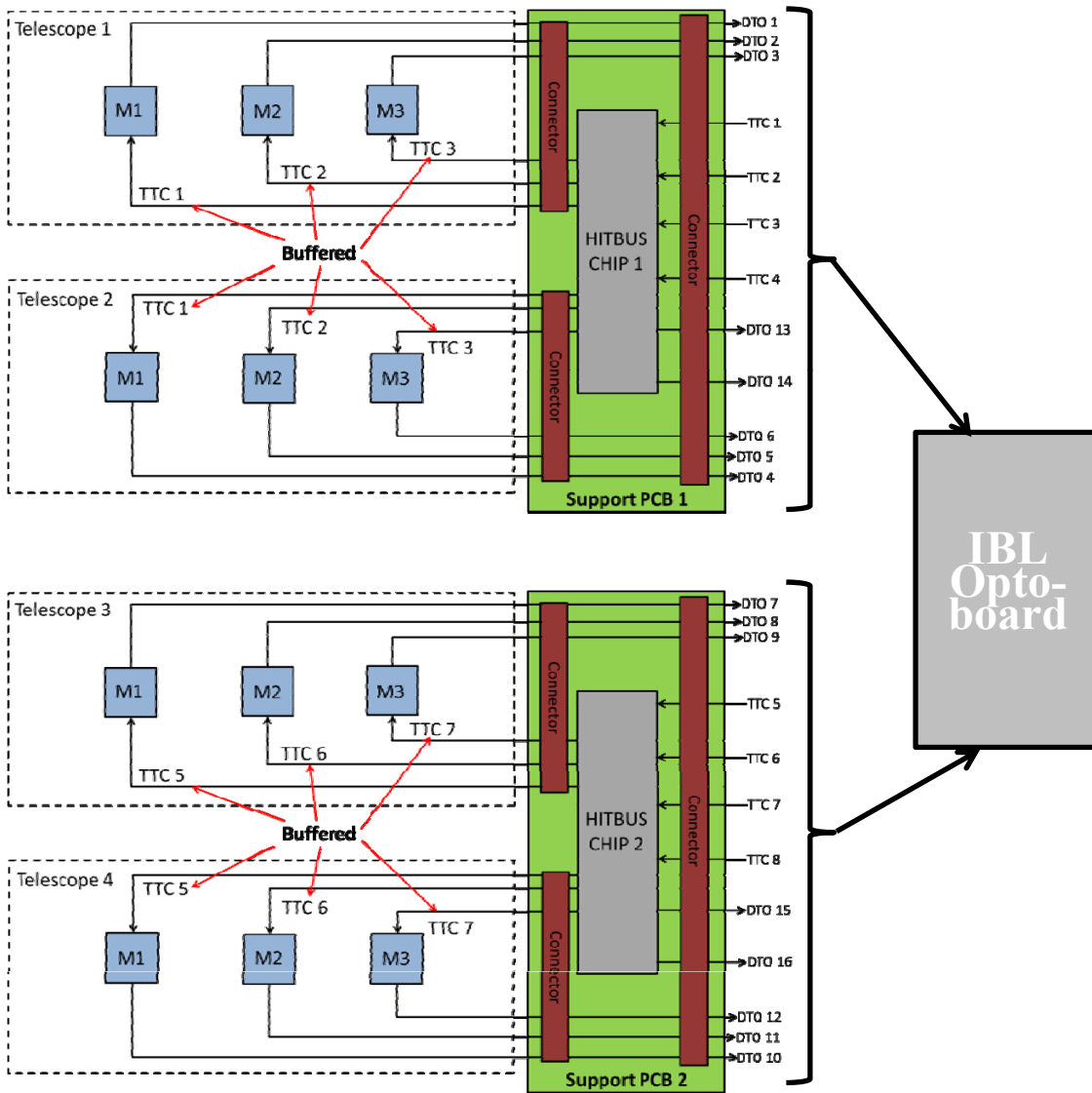
Each DBM hitbus chip services 2 telescopes so 4 chips needed for entire DBM

Use IBM 130nm 8RF CMOS  
Size: 4.59 mm x 1.06mm

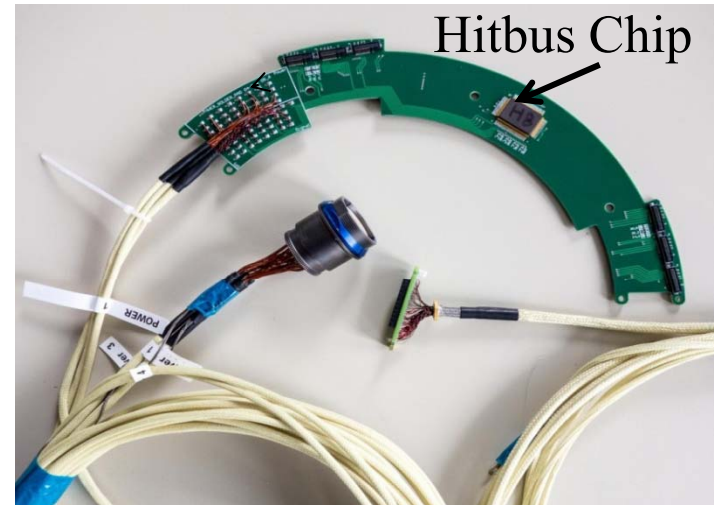
Incorporates shared circuit blocks from FEI4 collaboration & custom blocks designed at OSU



# Half DBM System Block Diagram



2 Support PCBs/side





# Hitbus Chip Irradiation

**Needed to certify that Hitbus Chip is rad hard**

Irradiated 2 Hitbus chips to  $4.3 \times 10^{15}$  p/cm<sup>2</sup> (115 Mrad)

Used 24 GeV proton beam at CERN

Both chips survived

Slight increase in supply current consumption

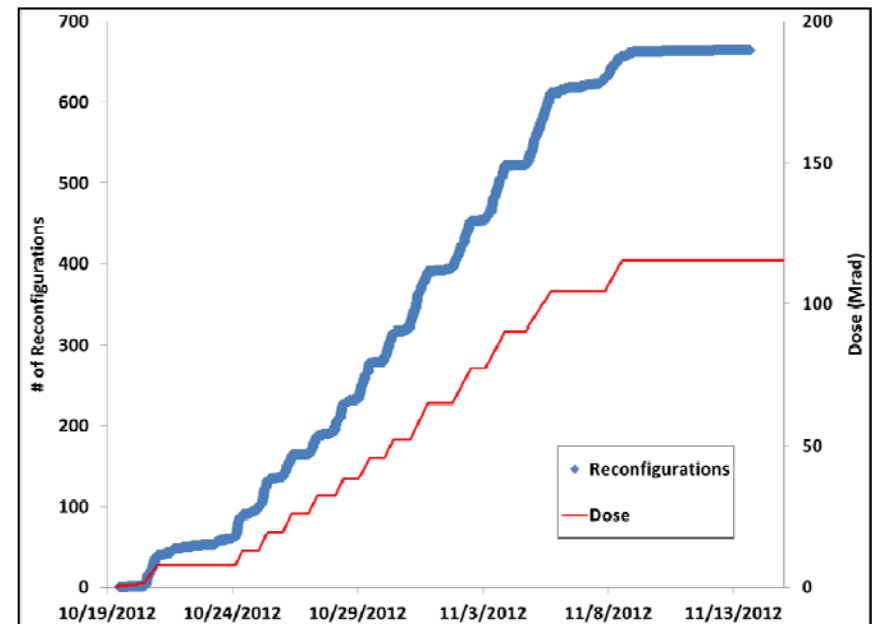
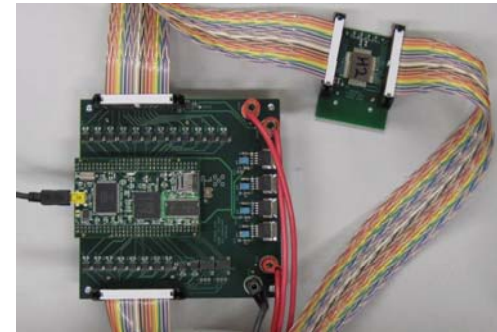
All functionality active during irradiation

Test system checked for SEU in the received data

Looked for flipped bits in SEU latches  
change of Hitbus desired function

Reconfigured the chip if error detected

Only 664 reconfiguration events needed  
(for both chips)







# Current Status of DBM



DBM currently being assembled at CERN

Potentially ~30 modules constructed

Modules still being processed at IZM

In the process of picking the best 24 modules to be installed

Measure I vs V to find range of operation

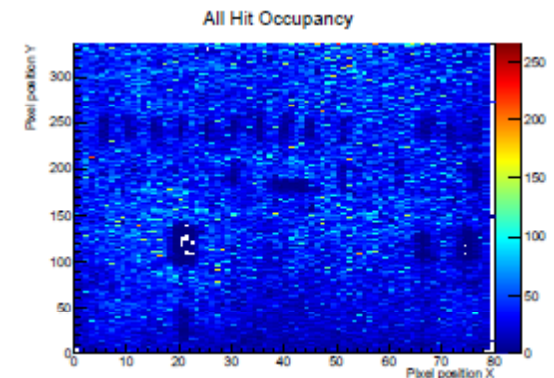
Sr90 source scan on each module

find disconnected pixels (bad bump bonds)

find noisy pixels

measure relative efficiency vs V and threshold

measure clusters vs threshold



Modules will be assembled into telescopes in ~ week

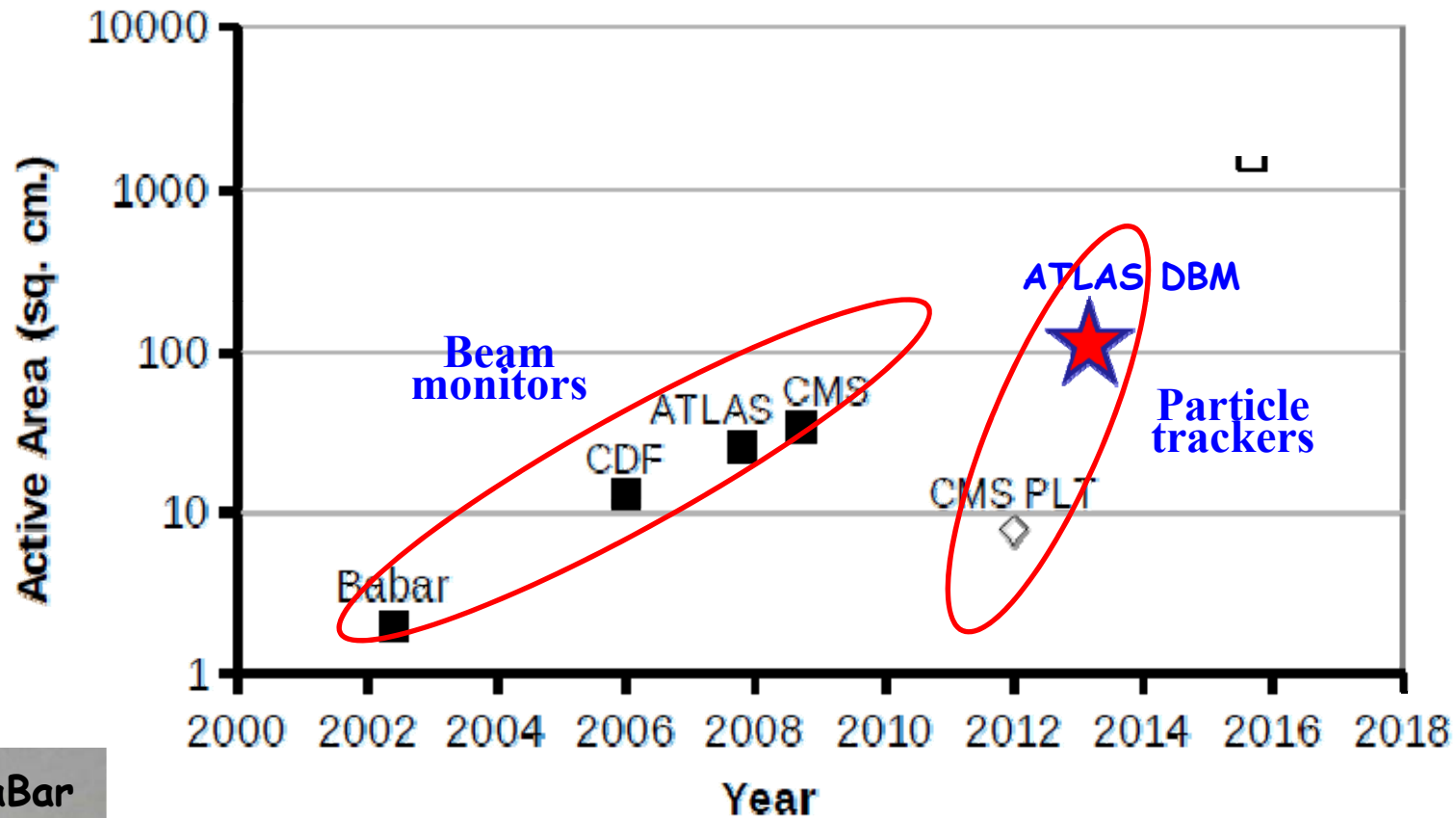
telescope = group of three modules, total of 8 telescopes in DBM

Telescopes installed in September



# DBM and Other Diamond Projects

DBM has  $\sim 6.25 \times 10^5$  channels  
(LEP's DELPHI pixel detector  $\sim 12 \times 10^5$  channels)



BaBar beam monitor:  
two pCVD diamonds  
1 cm x 1 cm x 500  $\mu$ m



# Summary

- Construction of the largest diamond pixel tracker underway
- Satisfies constraints for precision luminosity measurement
  - Bunch by bunch measurement
  - Background separation uses z resolution
- Should be robust against
  - Pile-up
  - Radiation damage

**ATLAS Diamond Beam Monitor TDR: ATU-DBM-001**



## Backup Slides



# Chemical Vapor Deposition Diamond

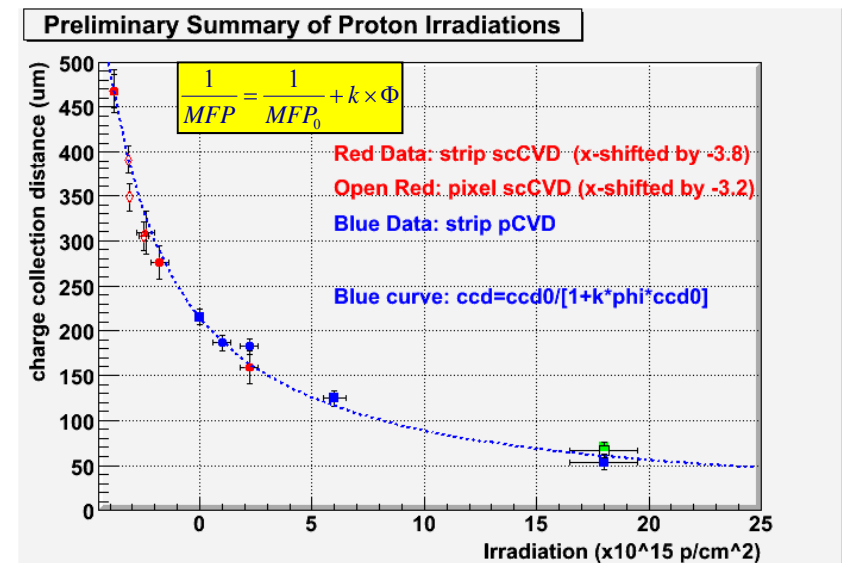


The properties of diamond make it interesting/useful for particle detectors:  
radiation hard, short collection time, low leakage current, high thermal conductivity

## Diamond as sensor material

Property	Diamond	Silicon
Band gap [eV] <input type="checkbox"/> Low leakage	5.5	1.12
Breakdown field [V/cm]	$10^7$	$3 \times 10^5$
Intrinsic resistivity @ R.T. [ $\Omega$ cm]	$> 10^{11}$	$2.3 \times 10^5$
Intrinsic carrier density [ $\text{cm}^{-3}$ ]	$< 10^3$	$1.5 \times 10^{10}$
Electron mobility [ $\text{cm}^2/\text{Vs}$ ]	1900	1350
Hole mobility [ $\text{cm}^2/\text{Vs}$ ]	2300	480
Saturation velocity [cm/s]	$0.9(e)-1.4(h) \times 10^7$	$0.82 \times 10^7$
Density [ $\text{g}/\text{cm}^3$ ]	3.52	2.33
Atomic number - Z	6	14
Dielectric constant - $\epsilon$ <input type="checkbox"/> Low cap	5.7	11.9
Displacement energy [eV/atom]	43	13-20
<input type="checkbox"/> Rad hard		
Thermal conductivity [W/m.K]	$\sim 2000$	150
<input type="checkbox"/> Heat spreader		
Energy to create e-h pair [eV]	13	3.61
Radiation length [cm]	12.2	9.36
Interaction length [cm]	24.5	45.5
Spec. Ionization Loss [MeV/cm]	6.07	3.21
Aver. Signal Created / $100 \mu\text{m}$ [ $e_0$ ]	3602	8892
<input type="checkbox"/> Low Noise, Low signal		
Aver. Signal Created / $0.1 X_0$ [ $e_0$ ]	4401	8323

## Radiation Studies

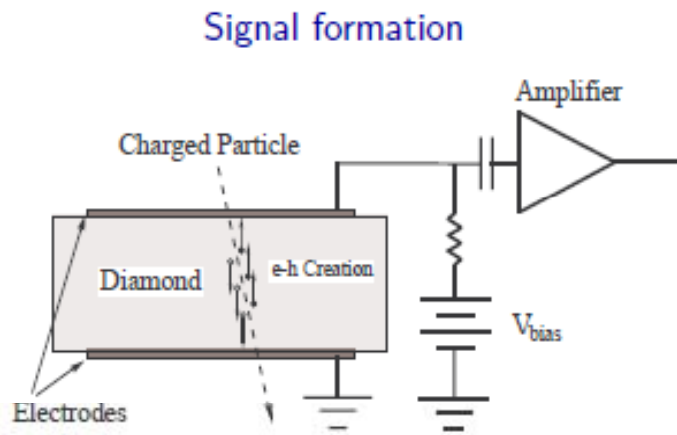


Single-crystal CVD & poly CVD fall along the same damage curve  
 Proton damage well understood  
 At all energies diamond is  $> 3x$  more radiation tolerant than silicon

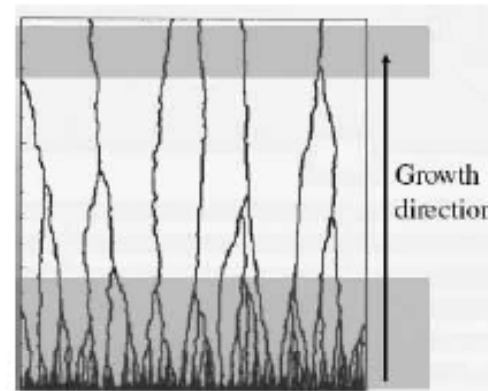


# Charge Collection in CVD Diamond

*Detectors Constructed with Diamond:*



pCVD Schematic Side View



- ◆  $d = (\mu_e \tau_e + \mu_h \tau_h) E$  where  $d$  = collection distance = ave. dist. e-h pair move apart
- ◆  $d = \mu E \tau = v \tau$ 
  - with  $\mu = \mu_e + \mu_h \rightarrow v = \mu E$
  - and  $\tau = \frac{\mu_e \tau_e + \mu_h \tau_h}{\mu_e + \mu_h}$
- ◆  $Q = \frac{d}{t} Q_0 \rightarrow$  for large charge need good collection distance - must maximize  $\mu$  and  $\tau$
- ◆  $I = Q_0 \frac{v}{d}$



# Diamond Specs

Property	Specifications
Sensor size	21mm x 18mm (active area 20mm x 16.8mm)
Sensor Thickness	400-500 microns
Minimum charge collection distance	200 microns
Minimum average charge	7200 electrons
Minimum collection distance/ charge after $2 \times 10^{15} \text{ cm}^{-2}$	100 microns/3600 electrons
Minimum signal/threshold after $2 \times 10^{15} \text{ cm}^{-2}$	3
Maximum operating voltage	1000 V
Maximum total leakage current (@1000 V)	100 nA



# Radiation Damage - Basics



Radiation induced effect	Diamond	Operational consequence	Silicon	Operational consequence
Leakage current	small & decreases	none	$I/V = \alpha \Phi$ $\alpha \sim 4 \times 10^{-17} \text{ A/cm}$	Heating Thermal runaway
Space charge	$\sim$ none	none	$\Delta N_{\text{eff}} \approx -\beta \Phi$ $\beta \sim 0.015 \text{ cm}^{-1}$	Increase of full depletion voltage
Charge trapping	Yes	Charge loss Polarization	$1/\tau_{\text{eff}} = \beta \Phi$ $\beta \sim 5-7 \times 10^{-16} \text{ cm}^2/\text{ns}$	Charge loss Polarization

Charge trapping the only relevant radiation damage effect

NIEL scaling questionable *a priori*

$E_{\text{gap}}$  in diamond 5 times larger than in Si

Many processes freeze out

Typical emission times order of months

Like Si at  $300/5 = 60 \text{ K}$  - Boltzmann factor

A rich source of effects and (experimental) surprises !

$$\frac{1}{\tau_{\text{eff}}} = \sum_t N_t (1 - P_t) \sigma_t v_{th}$$



## Summary of RD42 Test Beam Results for CVD Diamond

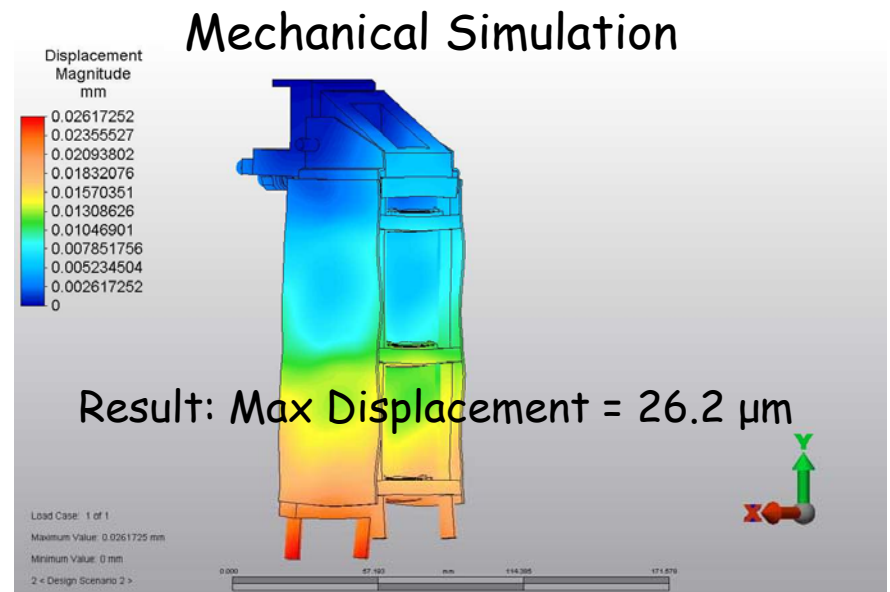
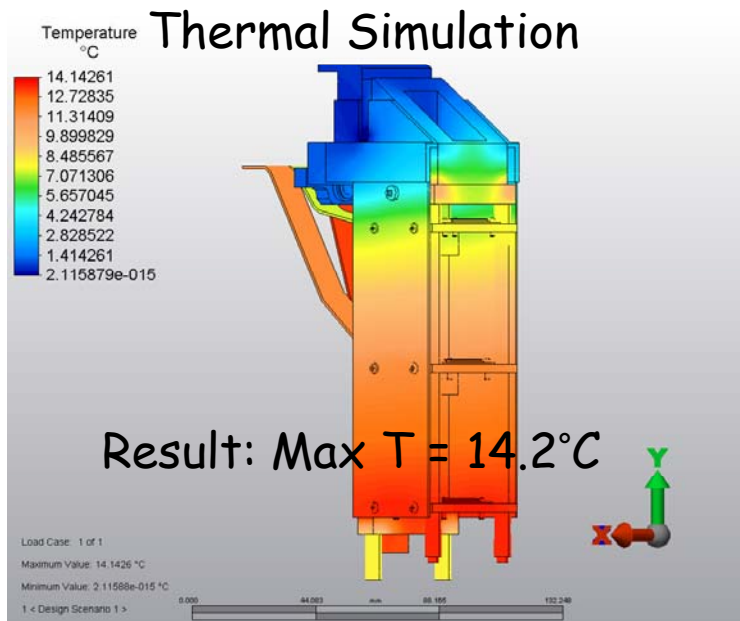
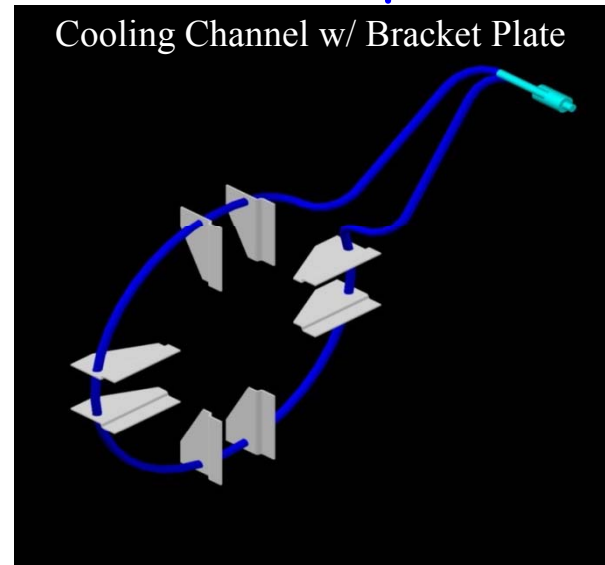
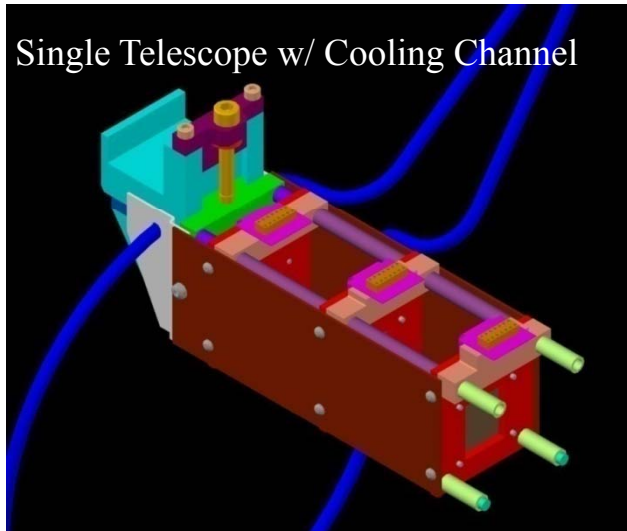
Particle	Energy	Relative k
p	24GeV	1.0
	800MeV	1.6-1.8
	70MeV	2.5-2.8
	25MeV	4.0-5.0
$\pi$	200MeV	2.5-3.0

k is relative damage constant



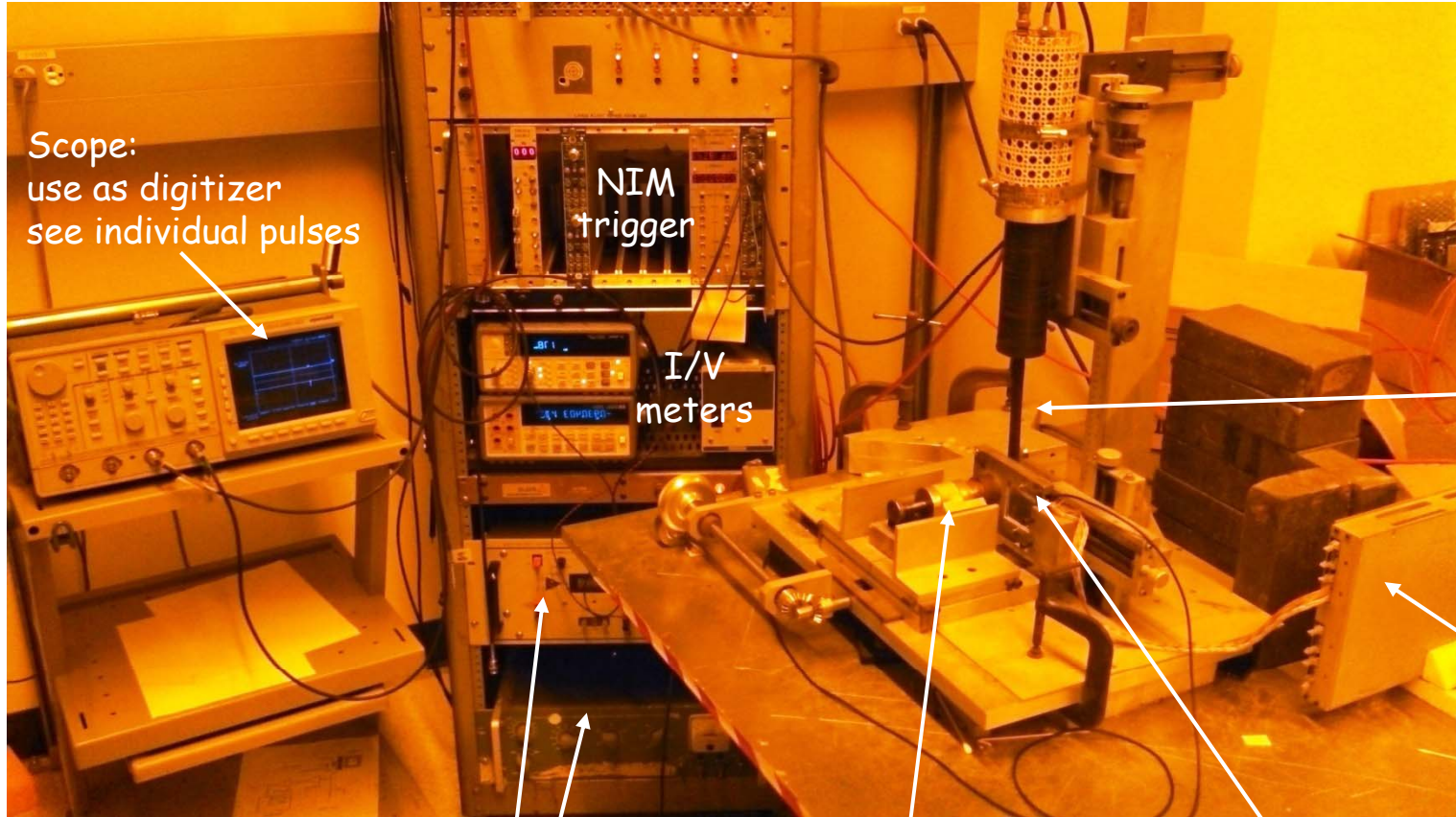
# The ATLAS DBM Concept

## Thermal & mechanical simulations complete





# CCD measurement with Sr90 @ OSU



Scope:  
use as digitizer  
see individual pulses

NIM  
trigger

I/V  
meters

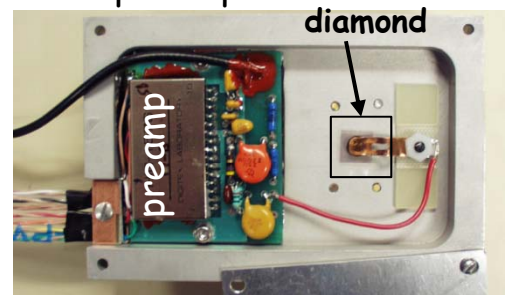
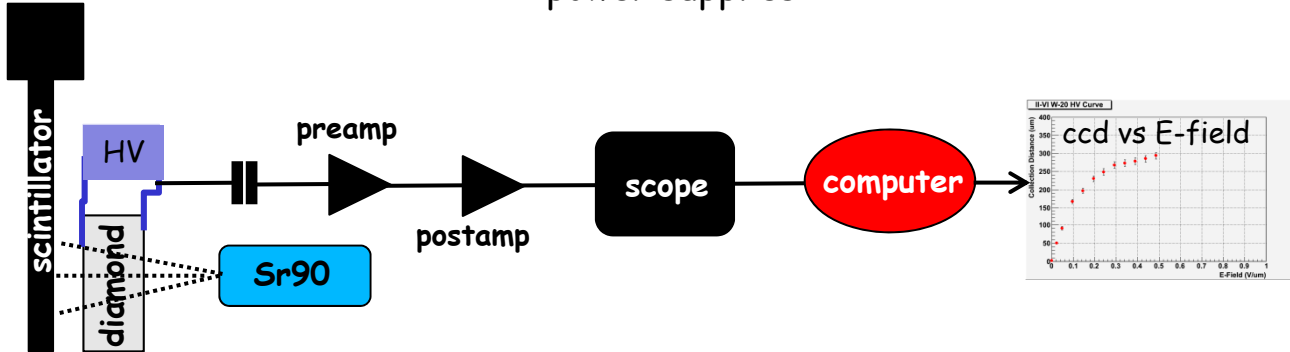
trigger  
scint.

postamp

power supplies

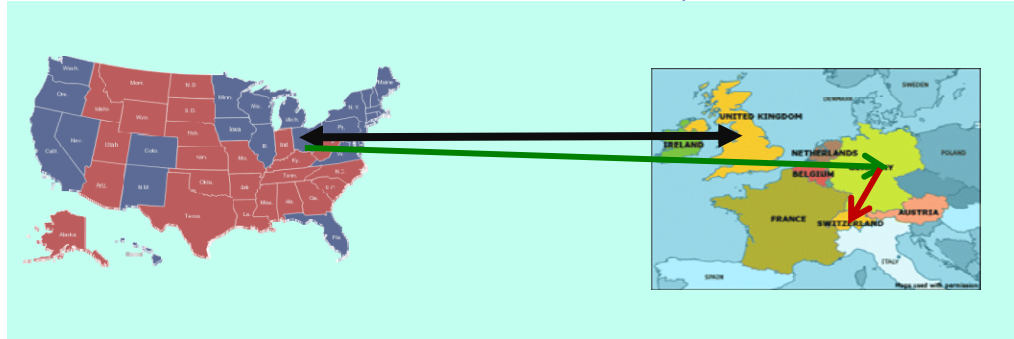
1mC Sr90 source

diamond holder  
and preamp





# DBM Diamond Sensor Qualification

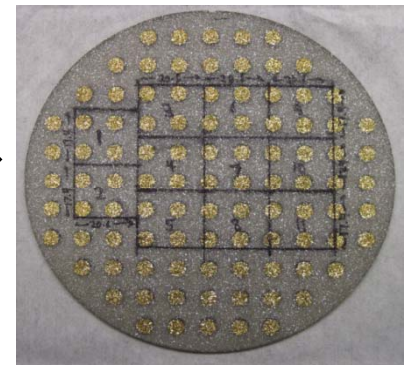
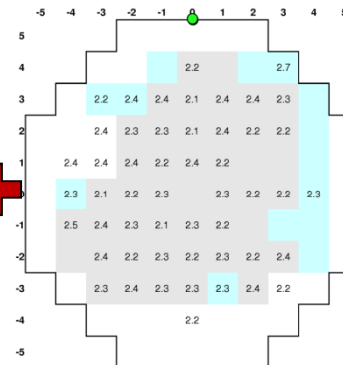
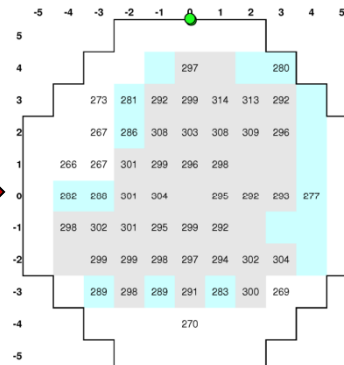


"Cut" map  
This wafer will be cut into 11 sensors



Map of charge collection distances

Map of current draw



Marks up E=0.66V/um  
CCD > 290 um  
CCD > 275 um

Marks up V=1000V  
CCD > 290 um  
CCD > 275 um

To IZM for bump bonding, etc

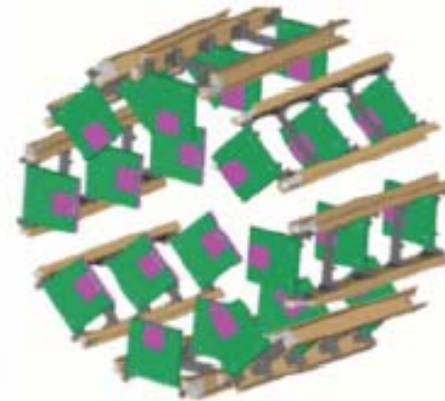
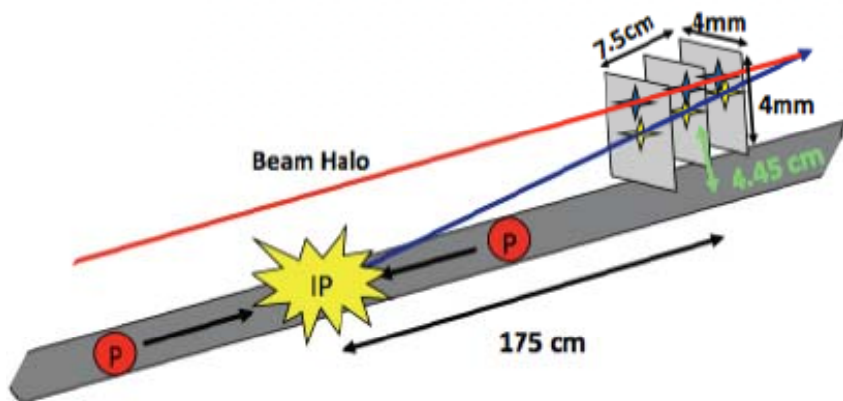
Back to OSU re-test with Sr90, metalize backplane

Back to manufacturer for dicing & thinning

# CMS Pixel Luminosity Telescope

Dedicated stand-alone luminosity monitor for CMS

- High precision bunch-by-bunch luminosity
- Array of 3-plane telescopes each end of CMS
- Single-crystal diamond pixel sensors
- Measure bunch-by-bunch 3-fold coincidence rate
- Pixel readout for tracking and diagnostics



Install in CMS in 2013-2014 shutdown